

TOSHIBA Photocoupler GaAs Ired & Photo-MOS FET

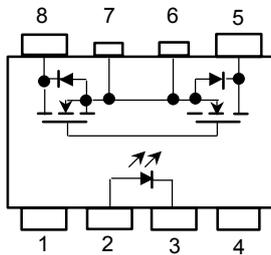
TLP3540

Memory Testers
 Logic IC Testers
 Data Recording Equipment
 Measuring Equipment

TLP3540 is a photorelay and consists of a GaAs infrared emitting diode optically coupled to a photo-MOSFET in a 8-pin DIP package (DIP8). This photorelay has characteristics of low-on resistance when it turns on. It is suitable for 48 V power line on / off switches.

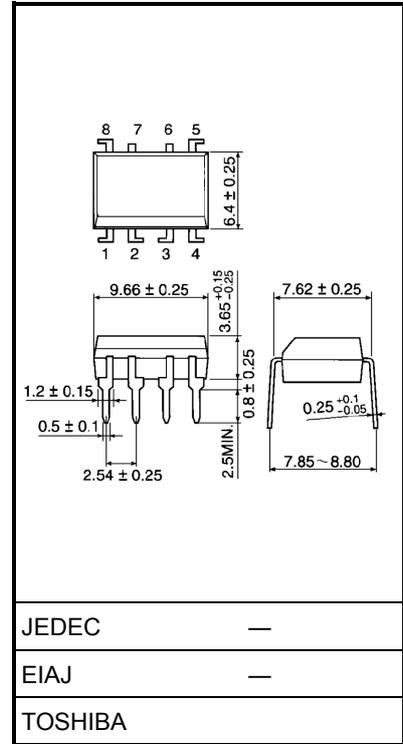
- 1-form-A
- Peak off-state voltage: 60V(min.)
- Trigger LED current: 5mA(max.)
- On-state current: 2A(max.)
- On-state resistance: 120mΩ(max.)
- Isolation voltage: 1500V_{rms}(min.)

Pin Configuration (top view)



- 1 : NC
- 2 : Anode
- 3 : Cathode
- 4 : NC
- 5 : Drain
- 6 : Source (shorten a pin)
- 7 : Source (shorten a pin)
- 8 : Drain

Unit in mm



Weight: 0.54 g

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Reverse voltage	V_R	6	V
	Junction temperature	T_j	125	°C
Detector	Off-state output voltage	V_{OFF}	60	V
	On-state current	I_{ON}	2	A
	Junction temperature	T_j	125	°C
Storage temperature		T_{stg}	-55~125	°C
Operating temperature		T_{opr}	-20~85	°C
Lead solder temperature (10 s)		T_{sol}	260	°C
Isolation voltage (AC, 1 min., R.H.≤ 60%) (Note 1)		BV_S	1500	V_{rms}

(Note 1): Device considered a two-terminal device: Pins 1, 2, 3 and 4 shorted together and pins 5 and 8 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{OFF}	—	—	48	V
Forward current	I_F	10	—	30	mA
On-state current	I_{ON}	—	—	2	A
Operating temperature	T_{opr}	25	—	50	°C

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 20 \text{ mA}$	1.0	1.2	1.4	V
	Reverse voltage	I_R	$V_R = 6 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	15	—	pF
Detector	Off-state current	I_{OFF}	$V_{OFF} = 20 \text{ V}, T_a = 50^\circ \text{C}$	—	1.0	4.0	nA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	600	1400	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Trigger LED current	I_{FT}	$I_{ON} = 1 \text{ A}$	—	—	5	mA
On-state resistance	R_{ON}	$I_{ON} = 1 \text{ A}, I_F = 10 \text{ mA}$	—	—	0.12	Ω

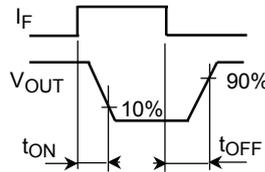
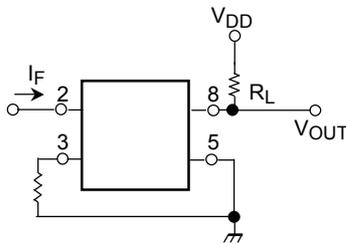
Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	C _S	V _S = 0V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	—	Ω
Isolation voltage	BV _S	AC, 1 minute	1500	—	—	V _{rms}
		AC, 1 second (in oil)	—	3000	—	
		DC, 1 minute (in oil)	—	3000	—	Vdc

Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Turn-on time	t _{ON}	R _L = 200Ω (Note2) V _{DD} = 20 V, I _F = 15 mA	—	—	5	ms
Turn-off time	t _{OFF}		—	—	3	

(Note 2): Switching time test circuit



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